Influence of substrate on molecular order for self‐assembled adlayers of CoPc and FePc

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Abstract

Self‐assembled metal phthalocyanine thin films are receiving considerable interest due to their potential technological applications. In this study, we present a comprehensive study of CoPc and FePc thin films of about 50 nm thickness on technologically relevant substrates such as SiO_v/Si , indium tin oxide (ITO) and polycrystalline gold in order to investigate the substrate induced effects on molecular stacking and crystal structure. Raman spectroscopic analysis reveals lower intensity for the vibrational bands corresponding to phthalocyanine macrocycle for the CoPc and FePc thin films grown on ITO as compared to SiO_v/Si due to the higher order of phthalocyanine molecules on SiO_x/Si . Atomic force microscopy analysis displays higher grain size for FePc and CoPc thin films on ITO as compared to SiO_x/Si and polycrystalline gold indicating towards the influence of molecule–substrate size for FePc and CoPc thin films on ITO as compared to SiO_x/Si and polycrys-
talline gold indicating towards the influence of molecule–substrate interactions
on the molecular stacking. Grazing incidence X-ray diffraction maps reveal that FePc and CoPc molecules adopt a combination of herringbone and brickstone arrangement on SiO_x/Si and polycrystalline gold substrate, which can have significant implications on the optoelectronic properties of the films due to unique molecular stacking.

KEYWORDS

metal phthalocyanine thin films, molecular stacking, molecule–substrate interactions, Raman spectroscopic analysis

1 | INTRODUCTION

Transition metal phthalocyanines (MPc) are the peculiar class of organic molecules, which due to their unique electrical and magnetic properties have the potential for optoelectronic and spintronic applications.[1] The properties of MPc are strongly influenced by polymorphism, crystal structure, and central metal atom.^[1,2] In recent years, considerable progress has been made in understanding the self-assembly of these molecules on metallic subconsiderable progress has been made in understanding strates with the aim to demonstrate interfacial electronic

properties. Moreover, due to their thermal stability at elevated temperatures, these molecules have been explored for their application in organic field‐effect transistors and solar cells.^[3,4] In view of impactful applications, it is crucial to obtain detailed information about the surface topography and preferred orientation of the crystallites. In addition, nature of substrate significantly influences the properties of the MPc thin films by controlling the molecular orientation during growth.[5]

The relative orientation of the molecules is driven by the properties of the MPC thin films by controlling the
molecular orientation during growth.^[5]
The relative orientation of the molecules is driven by
the fine interplay between molecule–substrate interactions

MPc thin films show different polymorphism depending on growth conditions and nature of substrate exhibiting triclinic or monoclinic symmetries.^[6] Surface properties of the substrate can significantly influence the growth mechanism and effectively control the crystal phase and film structure.^[7] The molecular arrangements of polymorphs influence the optical and transport properties of thin films significantly. It has been demonstrated that the absorption spectrum of MPc is red shifted in the triclinic structure due to increased intermolecular interactions in this phase.[8] In order to gain control over the organic thin films phase and morphology, organic molecular beam deposition has been effectively utilized to get good reproducibility. In addition, the interaction of the central metal atom with substrate effectively controls the organic thin films properties as the hybridization of metal 3d and macrocycle orbitals determine the energy separation between highest occupied molecular orbital and lowest unoccupied molecular orbital, which is a crucial parameter for optoelectronic devices.[8]

Micro Raman scattering spectroscopy has been utilized to study the polymorphism of CoPc and FePc on silicon at different growth temperatures.^[9] CoPc and FePc thin films show phase transition from α polymorph to β polymorph above 200 °C, and polarized Raman spectroscopy efficiently distinguishes the two phases. However, a comprehensive study for the room temperature deposition of FePc and CoPc on technologically relevant substrates is lacking. X‐ray absorption spectroscopy‐based study for the adsorption of CuPc on polycrystalline gold and indium tin oxide (ITO) shows that molecules adopt standing configuration on the substrates.^[10] However, detailed molecular arrangements have not been thoroughly understood. A multitechnique characterization approach is needed to gain the detailed information about the molecular phases. We have adopted grazing Individually understood. A multiteenfuque characteriza-
tion approach is needed to gain the detailed information
about the molecular phases. We have adopted grazing
incidence X-ray diffraction (GIXRD), atomic force microscopy (AFM), and Raman spectroscopy to study the solid state packing of MPc on three technologically significant substrates.

2 | EXPERIMENTAL SECTION

Thin films of CoPc and FePc of about 50 nm thickness were deposited on ITO (1.7 nm roughness), polycrystalline gold (Au, 0.3 nm roughness), and native oxide SiO_x on $Si(100)$ $(SiO_x$ roughness is 0.2 nm). The FePc and CoPc high purity polycrystalline powders (Sigma Aldrich) were evaporated from resistively heated quartz crucibles in UHV at the base pressure of 2×10^{-10} mbar and low deposition rate of 2 Å/min . All the depositions were performed at room temperature. The three substrates were rinsed in acetone before introducing them into the UHV chamber.

GIXRD measurements were performed at the X‐ray Diffraction beamline 5.2 at the Synchrotron Radiation Facility Elettra in Trieste, Italy. The beam was monochromatized at 1.4 Å. The samples were oriented biliarcion beamine 5.2 at the synchroton Kaulation
Facility Elettra in Trieste, Italy. The beam was
monochromatized at 1.4 Å. The samples were oriented
by means of a four-circle diffractometer following the standard procedures.^[11] Bidimensional diffraction patterns were recorded with a 2M Pilatus silicon pixel by means of a four-circle dimactometer following the
standard procedures.^[11] Bidimensional diffraction
patterns were recorded with a 2M Pilatus silicon pixel
X-ray detector (DECTRIS Ltd.) positioned perpendicular to the incident beam, at a distance of 130 mm from the sample. The sample inclination to the beam was about 1°, well over the critical angle for total external reflection of the substrate. Patterns were calibrated by means of a $LaB₆$ standard and integrated using the software Fit₂D,^[12] obtaining several series of powder like patterns, corrected for geometry, Lorentz and beam polarization effects. The 2theta range was spanned from 0.1° to 44.2° with resolution of 1.85 Å. Peaks positions were extracted by means of Fit2D in association with WinPLOTR.^[13]

The Raman measurements were performed in the reflection geometry. Continuous wave laser with a wavelength of 532 nm (Cobolt Samba, 50 mW, bandwidth 1 MHz) was used as excitation source. The 532 nm renection geometry. Continuous wave faser with a
wavelength of 532 nm (Cobolt Samba, 50 mW, bandwidth
1 MHz) was used as excitation source. The 532 nm
RazorEdge Dichroic™ laser-flat beam splitter and RazorEdge Dichroic™ laser-flat beam splitter and 532 nm RazorEdge® ultrasteep long-pass edge filter were used to direct the light into the microscope (Axiovert 200, Zeiss) and cut Rayleigh scattered light before the spectrometer(Shamrock SR‐750, Andor Technology plc.) respectively. The laser power on the sample was controlled by the neutral density filter (Thorlabs) and kept at 100 μ W. The acquisition time in all experiments was 600 s.

AFM measurements were performed in contact mode using Nanowizard II AFM (JPK), which allows scanning the sample in the range of $100 \times 100 \times 15$ µm. CSG 01 AFM measurements were performed in contact mode
using Nanowizard II AFM (JPK), which allows scanning
the sample in the range of $100 \times 100 \times 15$ µm. CSG 01
Silicon probes (NT-MDT) with a force constant of 0.05 N/m and 10 nm tip curvature were used.

3 | RESULTS

Figure 1 shows the 2D GIXRD reciprocal space maps for the deposition of the 50-nm-thick CoPc and FePc films on polycrystalline gold, SiO_x/Si , and ITO substrates. Reciprocal space maps show significant structural differences between depositions for the same molecule on three substrates. As shown in Figure 1a,d, the reciprocal space maps for the deposition of CoPc and FePc on

SiOx/Si, Au, and ITO at room temperature. ITO = indium tin oxide [Colour figure can be viewed at wileyonlinelibrary.com]

 SiO_x/Si exhibit multiple diffraction spots depicting highly crystalline and ordered structure. However, in case of polycrystalline Au, the diffraction spots are comparatively spread demonstrating that crystalline order is less pronounced on Au as compared to SiO_x/Si . It suggests that the FePc and CoPc crystallites disperse over a range of orientations and single stacking is not present.The comparison of reciprocal space maps for the CoPc and FePc deposition on SiO_x/Si and ITO unambiguously shows almost no detectable diffraction spots on ITO. This confirms that crystalline order is poor and MPc molecules are randomly oriented on ITO.The reciprocal space maps for the deposition of FePc and CoPc on SiO_x/Si show good resemblance with the recipcore on SO_{X}/ST show good resemblance with the reciprocal space maps for CuPc adsorbed on $ZnO(1\overline{1}00)$.^[14] The peaks observed around $Q_{xy} = 1.7, 1.9 \text{ Å}^{-1}$ and $Q_{xy} = 0.5$, 1.04 Å⁻¹ are assigned to brickstone (100) oriented phase and herringbone (200) oriented phase, respectively.[14] The observation of diffraction spots at similar values of Q_{xy} suggests that for 50-nm-thick CoPc and FePc films, the molecules are arranged in a mixed

phase. Although peaks are observed around $Q_{xy} = 1.7$, 1.9 Å⁻¹ and Q_{xy} = 0.5, 1.04 Å⁻¹ for the deposition of CoPc and FePc on Au substrate, diffraction spots appear less intense and tend to disperse as compared to SiO_x/Si due to reduced molecular order on polycrystalline Au.

Peak profile analysis has been performed after indexing the patterns, by the Hosemann model.^[15] The paracrystallinity analysis in Table S1 has been performed for the out of plane (OOP) direction assign similar paracrystallinity parameters for FePc thin films deposited on SiO_x/Si , Au, and ITO. This suggests that the molecular order does not differ significantly within domains, even though overall crystalline order is poor for deposition on ITO as compared to SiO_x/Si and Au. The paracrystallinity analysis has been performed for herringbone and brickstone phases, identified on diffraction patterns of CuPc deposition on ZnO(1100) by means of the SimDiffraction simulation software.^[16] Importantly, the analysis assigns nearly the same values for the two phases suggesting that herringbone and brickstone phases exhibit almost similar molecular order within domains. Paracrystallinity analysis performed for 4
within domains. Paracrystallinity analysis performed for
the in-plane (IP) direction reported in Table S1 assigns lower paracrystallinity parameters as compared to OOP direction for FePc and CoPc deposition on Au and SiO_x/Si indicating higher crystalline order within domains along the IP direction. Peak profile analysis shows that crystallites along OOP (i.e., in the h00) direction have larger dimensions but lower crystallinity than those in the IP direction. In the first case, arrangements of the molecules organized in not too rigidly bound columnar structures are the probable causes of the high value of the paracrystallinity parameter. However, in the of the indicentes organized in not too rightly bound
columnar structures are the probable causes of the high
value of the paracrystallinity parameter. However, in the
second case, molecules arrange edge-on with respect to the substrate and display better molecular order with a much lower paracrystallinity value. However, such arrangements of the molecules are more difficult to maintain in the long range, which results in smaller dimensions of the crystallites. Crystallite sizes reported in Table S1 are related to the coherence length in the specified crystallographic direction.

We have analyzed the topography of CoPc and FePc thin films using AFM as shown in Figure 2. FePc films on Au consist of densely packed, small elongated grains, which are randomly distributed. Notably, the grain density for the FePc thin film on Au is higher as compared to that of CoPc thin film on Au. These grains have good resemblance with CuPc thin films grains deposited on density for the Ferc thin film on Au is higher as compared
to that of CoPc thin film on Au. These grains have good
resemblance with CuPc thin films grains deposited on
the glass which adopts α-phase for room temperature deposition.^[17] The shape of grains is characteristic of α–
deposition.^[17] The shape of grains is characteristic of α– resemblance with Curc thin mins grains deposited on
the glass which adopts α-phase for room temperature
deposition.^[17] The shape of grains is characteristic of α-
phase as β-phase exhibits much longer grain size obtai for the deposition above 200 $^{\circ}$ C temperature.^[15] AFM images were analyzed using average crystallite size and root mean square (RMS) parameters as listed in Table 1. The average crystallite size and RMS values are highest for ITO as compared to Au and SiO_x/Si . Lower RMS

values for the deposition of FePc and CoPc on Au and SiO_x/Si indicate that molecules are uniformly distributed as compared to ITO. Due to weaker interactions of FePc and CoPc with ITO, the molecules tend to aggregate under the influence of intermolecular interactions, which results in higher surface roughness and average crystallite size. Scanning tunneling microscopy (STM) study for the room temperature deposition of FePc on Au(111) shows that molecules adopt columnar stacking structure on Au(111). The molecules lie on the substrate with small From temperature deposition of Ferc on Au(111) shows
that molecules adopt columnar stacking structure on
Au(111). The molecules lie on the substrate with small
tilt angle at low film thickness due to higher molecule- $Au(111)$. The molecules lie on the substrate with small tilt angle at low film thickness due to higher molecule–
substrate interactions.^[18] It is the strength of molecule– Au(111). The molecules he on the substrate with small
tilt angle at low film thickness due to higher molecule-
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substrate and molecule-molecule interactions t In the self-assembly of the molecule-
substrate interactions.^[18] It is the strength of molecule-
substrate and molecule-molecule interactions that
generally control the self-assembly of the molecules and first layer may direct the orientation of further layers. Comparatively lower crystallite size and RMS values for deposition of FePc and CoPc on Au and SiO_x/Si indicate that the influence of molecule–substrate interactions of FePc and CoPc on Au and SiO_x/Si indicate
that the influence of molecule–substrate interactions appear to be more pronounced for Au and SiO_x/Si as compared to ITO and significantly influence the film growth. Average crystallite size (surface and volume weighted) obtained by the GIXRD peak profile analysis agrees reasonably with the values obtained from AFM image analysis (Table 1) and follows a similar trend. Due to the poor crystalline order for the deposition of CoPc on ITO, the peak profile analysis could not be performed that is displayed in Table 1.

The Raman spectra of CoPc and FePc thin films of about 50 nm thickness deposited on Au, SiO_x/Si , and ITO are shown in Figures 3 and 4. All spectra are normalized to the intensity of vibrational mode at 1,532 cm−¹ and shifted vertically for clarity. No background subtraction was performed. The assignments of the peaks related to various vibrational modes are shown in Figures 3 and $4.^{[19-21]}$ No significant

temperature. ITO = indium tin oxide [Colour figure can be viewed at wileyonlinelibrary.com]

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(Benzene
ring defor $(C-N-C)$ Streching) $\frac{1}{5}$ (Macrocycle Breathing) ່ຮ 342 FePc_Au Ca 835 Normalized Raman Intensity 1142 cm⁻¹
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Breathing) cm 682 cm FePc Si 594 cm \overline{c} FePc ITO 400 600 800 1000 1200 1400 1600 1800 200 Wavenumber/cm⁻¹ CoPc_Au $(C-N-C)$ > 837 cm⁻¹
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(C α -C β) CoPc Si Normalized Raman Intensity CoPc_ITO ξ (Pyrrole
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FIGURE 3 Raman spectrum of FePc films on polycrystalline Au, SiOx/Si, and ITO. ITO $=$ indium tin oxide substrates [Colour figure can be viewed at wileyonlinelibrary.com]

FIGURE 4 Raman spectrum of CoPc films on polycrystalline Au, SiOx/Si, and ITO substrates. ITO $=$ indium tin oxide [Colour figure can be viewed at wileyonlinelibrary.com]

wavenumber shifts are observed for the Raman vibrational bands of CoPc and FePc deposited on these substrates. In general, the Raman spectrum of MPc is dominated by A_{1g} , B_{1g} , B_{2g} , and E_g modes corresponding to vibrations of the macrocycle, isoindole moieties, and metal–nitrogen bands of CoPc and FePc deposited on these substrates. In
general, the Raman spectrum of MPc is dominated by
 A_{1g} , B_{1g} , B_{2g} , and E_g modes corresponding to vibrations
of the macrocycle, isoindole moieties, and bands.^[21] The Raman bands in the 600 to 800 cm⁻¹ range for both FePc and CoPc films are associated with phthalocyanine macrocycle vibrational modes, and their relative intensities can be used to distinguish between polymorphic phases.[22] We measured the Raman spectra of FePc α and β powders and compared them with the spectrum of FePc thin film on Au as shown in Figure 5, in order to demonstrate the type of phase adopted by FePc thin films. The spectra are normalized and shifted vertically in order to demonstrate the variation in the relative intensities of demonstrate the type of phase adopted by FePc thin films.
The spectra are normalized and shifted vertically in order
to demonstrate the variation in the relative intensities of
vibrational modes at 684 and 750 cm^{−1}. Th

TABLE 1 Average grain size as obtained from atomic force microscopy (AFM) analysis compared with the crystallite size as obtained from TABLE 1 Average grain size as obtained from atomic force mic
grazing incidence X-ray diffraction (GIXRD) peak profile analysis

spectra are normalized to the intensity of vibrational mode spectra are normalized to the intensity of vibrational mode
at about 1,532 cm^{−1}, while β-phase spectrum is normalized to vibrational mode at about 1,761 cm⁻¹. The relative spectra are normanzed to the mensity of vibrational mode
at about 1,532 cm⁻¹, while β-phase spectrum is normal-
ized to vibrational mode at about 1,761 cm⁻¹. The relative
intensity of the peak at about 750 cm⁻¹ for is lower than the peak at about 684 cm^{-1} while the intenintensity of the peak at about 750 cm⁻¹ for FePc α-powder
is lower than the peak at about 684 cm⁻¹ while the intensity ratio is reversed for β-phase.^[22] In case of FePc thin film deposited on Au, the intensity of the peak at about 750 cm^{-1} is significantly larger than at about 684 cm^{-1} testhe state of state that the intensity of the peak at about
 750 cm^{-1} is significantly larger than at about 684 cm⁻¹ tes-

tifying that thin film adopts α -phase. In addition, considerable modifications for the vibrational Raman bands are tifying that thin film adopts α -phase. In addition, considerable modifications for the vibrational Raman bands are observed for the bulk powders α and β -phase as compared thin films α phase. In addition, consider-
able modifications for the vibrational Raman bands are
observed for the bulk powders α and β -phase as compared
to thin films α-phase showing the influence of unique molecular stacking. Erved for the burk powders α and β -phase as compared
thin films α -phase showing the influence of unique
lecular stacking.
In order to investigate the molecular stacking of self-

assembled thin films of CoPc and FePc, we have monitored the intensity of mode corresponding to macrocycle breathing vibration at 685 cm⁻¹ as this mode most probably is influenced by intermolecular interactions. Figure 6 shows the variation of this mode with respect to film roughness as obtained from AFM analysis (Table 1). In order to study intensity variation, the values of the macrocycle breathing mode intensities for the deposition of CoPc and FePc on SiOx/Si, Au, and ITO are extracted from normalized spectra shown in Figures 3 and 4. The intensity of the macrocycle breathing mode is minimum for the deposition of FePc and CoPc on ITO. The intensity variation follows the trend of surface roughness in case of CoPc deposition while for the FePc deposition on Au it shows maximum value. Surface roughness, lattice structure, and chemical interaction between adsorbed molecules and substrate are the factors influencing molecular orientation and films growth.^[23] X-ray absorption studies showed that MPc molecules tend to adopt a standing configuration with increasing substrate roughness.[23] As the intensity of Raman bands depends on crystal orientation and polarization geometry, $[24]$ we can associate the intensity variation of the macrocycle

FIGURE 5 Raman spectrum of the FePc α and β crystalline powders along **FIGURE 5** Raman spectrum of the
FePc α and β crystalline powders along
with α -phase FePc thin film on Au [Colour figure can be viewed at wileyonlinelibrary. com]

FIGURE 6 Variation of macrocycle breathing mode normalized intensity with film roughness [Colour figure can be viewed at wileyonlinelibrary.com]

breathing mode to the average molecular orientation. Due to the higher surface roughness of ITO and weaker chemical interaction as compared to SiO_x/Si and Au, disordered, standing configuration of molecules can be expected. Moreover, in the absence of stronger molechemical interaction as compared to SO_x/SI and Au, disordered, standing configuration of molecules can be expected. Moreover, in the absence of stronger molecule–substrate interactions, weaker intermolecular interactions dominate and molecules adopt standing configuration.[25] Comparatively higher Raman intensity for the deposition of FePc on Au as compared to CoPc in

Figure 6 can be associated with the different interaction with the substrate and growth mechanism induced by the different central metal atom. Importantly, dissimilarity in the FePc and CoPc growth mechanism on Au is evident from AFM analysis (Figure 2); FePc grains are elongated and dense as compared to spherical CoPc grains. In the case of the deposition of CuPc on Au, it has been observed that molecules adopt lying configuration with respect to the substrate during initial growth of the first few layers due to the higher interaction of π electron cloud with the metallic substrate.^[26] However, for the deposition on ITO, it is not expected that CoPc molecules adopt lying configuration in the electron cloud with the metallic substrate. Thowever,
for the deposition on ITO, it is not expected that
CoPc molecules adopt lying configuration in the
absence of stronger molecule–substrate interactions. In addition, AFM analysis shows that grain size and surface roughness are relatively higher for ITO as compared to Au and SiO_x/Si . Thus, we can associate the observed variation in the macrocycle breathing mode intensity to the unique molecular orientation adopted by CoPc and FePc and $SU_X/51$. Thus, we can associate the observed variation
in the macrocycle breathing mode intensity to the unique
molecular orientation adopted by CoPc and FePc
molecules under the influence of molecule–substrate interactions, substrate roughness, and lattice structure.

4 | CONCLUSIONS

In summary, the structural properties of FePc and CoPc film of 50 nm thickness deposited on Au, SiO_x/Si , and ITO substrates have been studied by GIXRD, revealing the coexistence of herringbone and brickstone arrangements in ordered crystallites, whose dimensions and morphologies depend on the substrate and central atom. Moreover, GIXRD analyses reveal that CoPc and FePc thin films deposited on ITO are the least ordered. Raman spectroscopic analysis shows that the macrocycle breathing mode of FePc and CoPc is sensitive to the molecular stacking in the films that is influenced by an interaction of the central metal atom with the substrate and substrate roughness. Our achievements can help a better understanding of the topography and structure of MPc films, which have significant implications for their magnetic and optoelectronic properties.

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